

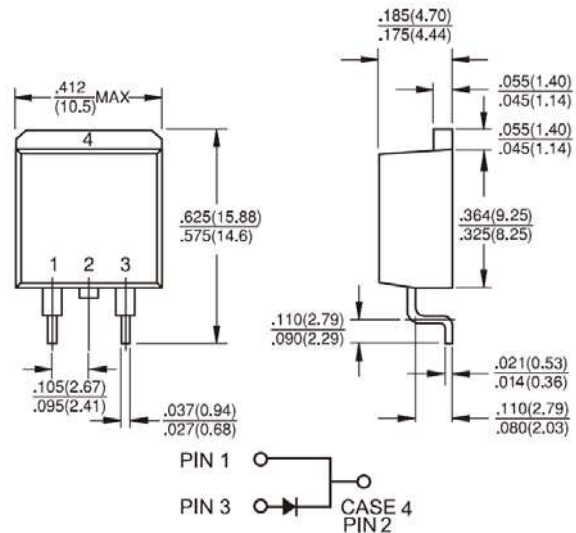


Features

- ✧ UL Recognized File #E-326854
- ✧ Glass passivated junction chip
- ✧ High efficiency, low VF
- ✧ High current capability
- ✧ High reliability
- ✧ High surge current capability
- ✧ Low power loss
- ✧ For use in low voltage, high frequency inverter, Free wheeling, and polarity protection application
- ✧ Green compound with suffix "G" on packing code & prefix "G" on datecode
- ✧ Qualified as per AEC-Q101

Mechanical Data

- ✧ Case: D²PAK Molded plastic
- ✧ Epoxy: UL 94V-0 rate flame retardant
- ✧ Terminals: Pure tin plated, lead free, solderable per MIL-STD-202, Method 208 guaranteed
- ✧ Polarity: As marked
- ✧ High temperature soldering: 260°C /10 seconds/.16",(4.06mm) from case
- ✧ Weight: 1.33 grams



Dimensions in inches and (millimeters)

Marking Diagram



- SFAS80XG = Specific Device Code
- G = Green Compound
- Y = Year
- WW = Work Week

Maximum Ratings and Electrical Characteristics

Rating at 25 °C ambient temperature unless otherwise specified.
Single phase, half wave, 60 Hz, resistive or inductive load.
For capacitive load, derate current by 20%

Type Number	Symbol	SFAS 801G	SFAS 802G	SFAS 803G	SFAS 804G	SFAS 805G	SFAS 806G	SFAS 807G	SFAS 808G	Unit
Maximum Repetitive Peak Reverse Voltage	V_{RRM}	50	100	150	200	300	400	500	600	V
Maximum RMS Voltage	V_{RMS}	35	70	105	140	210	280	350	420	V
Maximum DC Blocking Voltage	V_{DC}	50	100	150	200	300	400	500	600	V
Maximum Average Forward Rectified Current @ $T_C=100^\circ C$	$I_{F(AV)}$	8.0								A
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I_{FSM}	125								A
Maximum Instantaneous Forward Voltage @ 8.0A	V_F	0.95			1.3		1.7			V
Maximum Reverse Current @ Rated VR $T_A=25^\circ C$ $T_A=100^\circ C$	I_R					10		400		uA
Maximum Reverse Recovery Time (Note 1)	T_{rr}					35				nS
Typical Junction Capacitance (Note 2)	C_j	80			60					pF
Typical Thermal Resistance	$R_{\theta JC}$	2.2								°C/W
Operating Temperature Range	T_J	- 65 to + 150								°C
Storage Temperature Range	T_{STG}	- 65 to + 150								°C

Note 1: Reverse Recovery Test Conditions: $I_F=0.5A$, $I_R=1.0A$, $I_{RR}=0.25A$

Note 2: Measured at 1 MHz and Applied Reverse Voltage of 4.0V D.C.

RATINGS AND CHARACTERISTIC CURVES (SFAS801G THRU SFAS808G)

FIG.1 FORWARD CURRENT DERATING CURVE

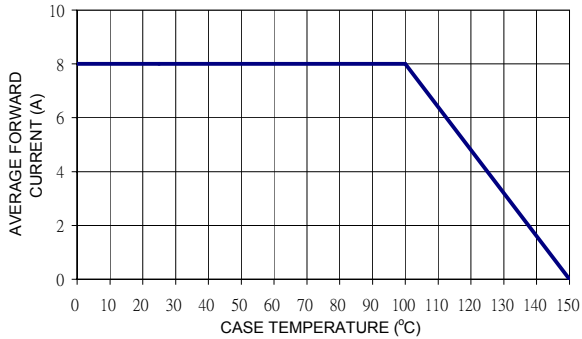


FIG. 2 TYPICAL REVERSE CHARACTERISTICS

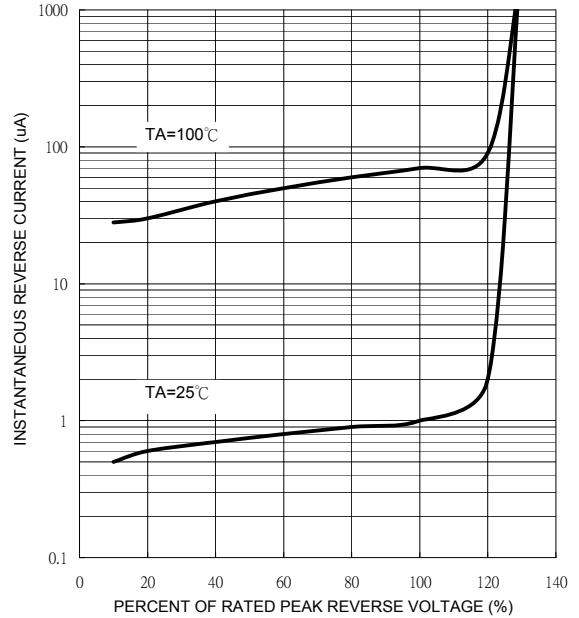


FIG. 3 MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

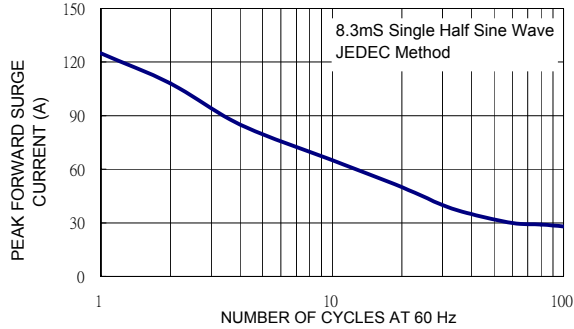


FIG. 5 TYPICAL FORWARD CHARACTERISTICS

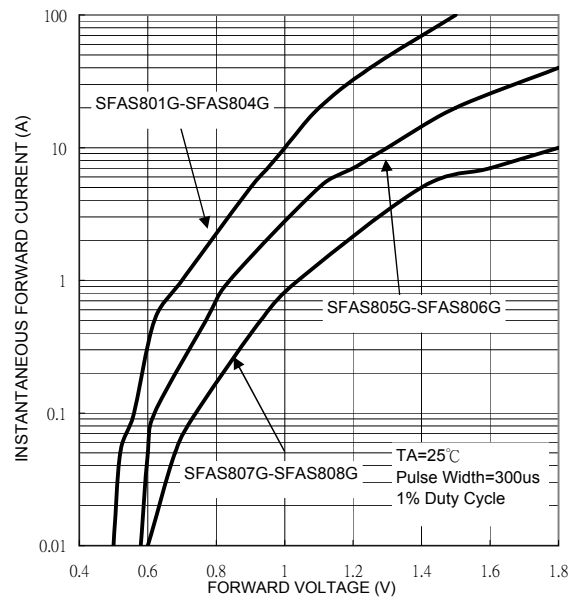


FIG. 4 TYPICAL JUNCTION CAPACITANCE

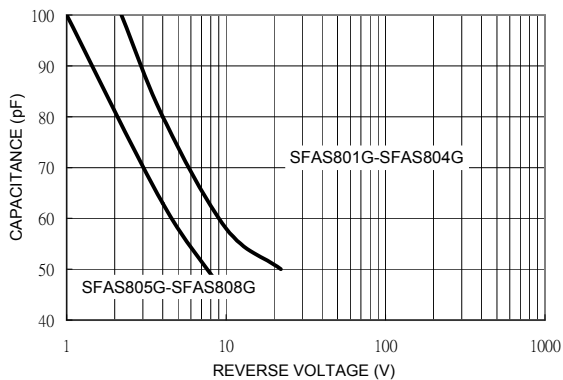


FIG.6- REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM

